








	<h2>IPD50R399CP</h2>
	<p>Hersteller-Teilenummer: IPD50R399CP</p> <p>Hersteller / Marke: International Rectifier (Infineon Technologies)</p> <p>Teil der Beschreibung: MOSFET N-CH 550V 9A TO-252</p> <p>Datenblätter:  IPD50R399CP.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 38803 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPD50R399CP
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 550V 9A TO-252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	38803 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	83W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	550V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Tc)
Rds On (Max) @ Id, Vgs	399 mOhm @ 4.9A, 10V
VGS (th) (Max) @ Id	3.5V @ 330µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	890pF @ 100V
Verpackung	Tape & Reel (TR)










IPD50R399CP ist neu im Original, Suche IPD50R399CP Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD50R399CP International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD50R399CP: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPD50R380CE International Rectifier (Infineon Technologies) IPD50R380CE Infineon Technologies</p>	 <p>IPD50R399CPATMA1 International Rectifier (Infineon Technologies) LOW POWER_LEGACY</p>	 <p>IPD50R3K0CE INFIENO IPD50R3K0CE INFIENO</p>	 <p>IPD50R3K0CEAUMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 500V 1.7A PG-TO-252</p>
 <p>IPD50R380CEBTMA1 International Rectifier (Infineon Technologies) MOSFET N CH 500V 9.9A PG-TO252</p>	 <p>IPD50R380CEATMA1 International Rectifier (Infineon Technologies) MOSFET N CH 500V 9.9A PG-TO252</p>	 <p>IPD50R380CEAUMA1 International Rectifier (Infineon Technologies) MOSFET NCH 500V 14.1A TO252</p>	 <p>IPD50R3K0CEBTMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 500V 1.7A PG-TO-252</p>

heiße Teile

Mehr

 IPD50N04S08	 IPD50N04S3-08	 IPD50N04S3-09	 IPD50N04S4-08	 IPD50N04S4-10
 IPD50N04S4L-08	 IPD50N06L13	 IPD50N06S2-14	 IPD50N06S2L-13	 IPD50N06S3-09
 IPD50N06S3-15	 IPD50N06S3L-06	 IPD50N06S3L-08	 IPD50N06S3L-13	 IPD50N06S4-09
 IPD50N06S4-12	 IPD50N06S4L-08	 IPD50N06S4L-12	 IPD50N10S3L-16	 IPD50P03P4L-04
 IPD50P03P4L-11	 IPD50P04P4-13	 IPD50P04P4L-11	 IPD50R280CE	 IPD50R380CE
 IPD50R500CE	 IPD50R520CP	 IPD50R650CE	 IPD50R950CE	 IPD530N15N3
 IPD530N15N3G	 IPD530N15NG	 IPD600N25N3G	 IPD60N10S4L-12	 IPD60R1K0CE
 IPD60R1K4C6	 IPD60R1K5CE	 IPD60R2K0C6	 IPD60R360P	 IPD60R380C6
 IPD60R380E6	 IPD60R380P6	 IPD60R385CP	 IPD60R3K3C6	 IPD60R400CE
 IPD60R450E6	 IPD60R520C6	 IPD60R520CP	 IPD60R600C6	 IPD60R600CP

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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